

8 x 4 Wideband Video Crosspoint Array

DESCRIPTION

The DG884 contains a matrix of 32 T-switches configured in an 8 x 4 crosspoint array. Any of the IN/OUT pins may be used as an input or output. Any of the IN pins may be switched to any or simultaneously to all OUT pins.

The DG884 is built on a proprietary D/CMOS process that combines low capacitance switching DMOS FETs with low power CMOS control logic and drivers. The ground lines between adjacent signal input pins help to reduce crosstalk. The low on-resistance and low on-capacitance of the DG884 make it ideal for video and wideband signal routing.

Control data is loaded individually into four Next Event latches. When all Next Event latches have been programmed, data is transferred into the Current Event latches via a SALVO command. Current Event latch data readback is available to poll array status.

Output disable capabilities make it possible to parallel multiple DG884s to form larger switch arrays. DIS outputs provide control signals used to place external buffers in a power saving mode.

For additional information see applications note AN504 (FaxBack document number 70610).

FEATURES

- · Routes Any Input to Any Output
- · Wide Bandwidth: 300 MHz
- Low Crosstalk: 85 dB at 5 MHz
- Double Buffered TTL-Compatible Latches with Readback
- Low r_{DS(on)}: 45 Ω
- Optional Negative Supply

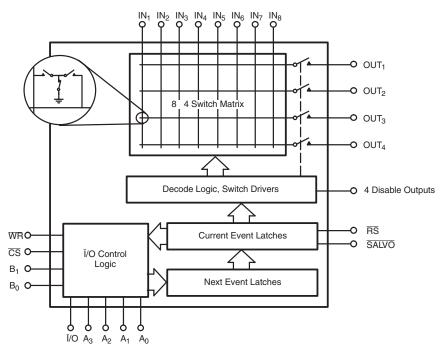
BENEFITS

- · Reduced Board Space
- Improved System Bandwidth
- · Improved Channel Off-Isolation
- Simplified Logic Interfacing
- · Allows Bipolar Signal Swings
- · Reduced Insertion Loss
- · High Reliability

APPLICATIONS

- · Wideband Signal Routing and Multiplexing
- High-End Video Systems
- NTSC, PAL, SECAM Switchers
- Digital Video Routing
- ATE Systems

FUNCTIONAL BLOCK DIAGRAM



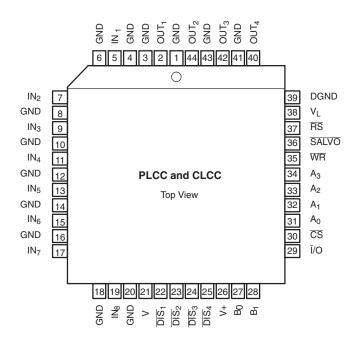
^{*} Pb containing terminations are not RoHS compliant, exemptions may apply







PIN CONFIGURATION AND ORDERING INFORMATION



ORDERING INFORMATION						
Temp Range	Package	Part Number				
- 40 to 85 °C	44-Pin PLCC	DG884DN DG884DN-E3				

TRUT	RUTH TABLE I									
RS	Ī/O	CS	WR	SALVO	Actions					
1	0	1		1	No change to Next Event latches					
1	0	0	T	1	Next Event latches loaded as defined in table below					
1	0	0	0	1	Next Event latches are transparent					
1	0	0		1	Next Event data latched-in					
1	0	Х	1	₹_	Data in all Next Event latches is simultaneously loaded into the Current Event latches, i.e., all new crosspoint addresses change simultaneously when SALVO goes low					
1	0	0	Х	0	Current Event latches are transparent					
1	0	Х	1		Current Event data latched-in					
1	0	0	0	0	Both next and Current Event latches are transparent					
1	1	1	1	1	A ₀ , A ₁ , A ₂ , A ₃ - High impedance					
1	1	0	1	1	A ₀ , A ₁ , A ₂ , A ₃ become outputs and reflect the contents of the Current Event latches B ₀ , B ₁ determine which Current Event latches are being read					
0	Х	Х	1	1	All crosspoints opened (but data in Next Event latches is preserved)					

All other states are not recommended.







TRUTH TABLE II									
WR	B ₁	B ₀	A ₃	A ₂	A ₁	A ₀	Next Event Latches		
				0	0	0	IN ₁ to OUT ₁ Loaded		
				0	0	1	IN ₂ to OUT ₁ Loaded		
				0	1	0	IN ₃ to OUT ₁ Loaded		
				0	1	1	IN ₄ to OUT ₁ Loaded		
	0	0	1	1	0	0	IN ₅ to OUT ₁ Loaded		
				1	0	1	IN ₆ to OUT ₁ Loaded		
				1	1	0	IN ₇ to OUT ₁ Loaded		
				1	1	1	IN ₈ to OUT ₁ Loaded		
			0	Х	Х	Х	Turn Off OUT ₁ Loaded		
				0	0	0	IN ₁ to OUT ₂ Loaded		
				0	0	1	IN ₂ to OUT ₂ Loaded		
				0	1	0	IN ₃ to OUT ₂ Loaded		
				0	1	1	IN ₄ to OUT ₂ Loaded		
	0	1	1	1	0	0	IN ₅ to OUT ₂ Loaded		
				1	0	1	IN ₆ to OUT ₂ Loaded		
				1	1	0	IN ₇ to OUT ₂ Loaded		
				1	1	1	IN ₈ to OUT ₂ Loaded		
0			0	Х	Х	Х	Turn Off OUT ₂ Loaded		
Ü				0	0	0	IN ₁ to OUT ₃ Loaded		
				0	0	1	IN ₂ to OUT ₃ Loaded		
				0	1	0	IN ₃ to OUT ₃ Loaded		
				0	1	1	IN ₄ to OUT ₃ Loaded		
	1	0	1	1	0	0	IN ₅ to OUT ₃ Loaded		
					IN ₆ to OUT ₃ Loaded				
				1	1	0	IN ₇ to OUT ₃ Loaded		
				1	1	1	IN ₈ to OUT ₃ Loaded		
			0	Х	Х	Х	Turn Off OUT ₃ Loaded		
				0	0	0	IN ₁ to OUT ₄ Loaded		
				0	0	1	IN ₂ to OUT ₄ Loaded		
				0	1	0	IN ₃ to OUT ₄ Loaded		
] .	0	1	1	IN ₄ to OUT ₄ Loaded		
	1	1	1	1	0	0	IN ₅ to OUT ₄ Loaded		
				1	0	1	IN ₆ to OUT ₄ Loaded		
				1	1	0	IN ₇ to OUT ₄ Loaded		
				1	1	1	IN ₈ to OUT ₄ Loaded		
Notes:			0	X	Х	Х	Turn Off OUT ₄ Loaded		

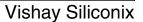
Notes: When $\overline{WR} = 0$ Next Event latches are transparent. Each crosspoint is addressed individually, e.g., to connect IN₁ to OUT₁ thru OUT₄ requires A₀, A₁, A₂ = 0 to be latched with each combination of B₀, B₁. When $\overline{RS} = 0$, all four \overline{DIS} outputs pull low simultaneously.

ABSOLUTE MAXIMUM RATINGS						
Parameter		Limit	Unit			
V+ to GND		- 0.3 to 21				
V+ to V-		- 0.3 to 21				
V- to GND		- 10 to 0.3				
V _L to GND		0 to (V+) + 0.3	V			
Digital Inputs		(V-) - 0.3 to (V _L) + 0.3 or 20 mA, whichever occurs first				
V_S, V_D		(V-) - 0.3 to (V-) + 14 or 20 mA, whichever occurs first				
Current (any terminal) Continuou	IS	20				
Current (S or D) Pulsed 1 ms 10	% Duty	40				
Storage Temperature	(A Suffix)	- 65 to 150				
Storage remperature	(D Suffix)	- 65 to 125	°C			
Operating Temperature	(A Suffix)	- 55 to 125	O			
Operating remperature	(D Suffix)	- 40 to 85				
Power Dissipation (Package) ^a	44-Pin Quad J Lead PLCCb	450	mW			
rowei Dissipation (Package)	44-Pin Quad J Lead Hermetic CLCC ^c	1200	11100			

Notes:
a. All leads soldered or welded to PC Board.
b. Derate 6 mW/°C above 75 °C
c. Derate 16 mW/°C above 75 °C.



					uffix	D Suffix		Hait		
		Unless Specified V+ = 15 V, V- = - 3 V $V_L = 5 V, \overline{RS} = 2.0 V$			- 55 to	125 °C	- 40 to	85 °C	Un	
Parameter	Symbol	\overline{SALVO} , \overline{CS} , \overline{WR} , $\overline{I/O} = 0.8 \text{ V}$	Temp ^b	Тур ^с	Min ^d	Max ^d	Min ^d	Max ^d	Un	
Analog Switch		2,12,0,00,111,10	1.06	- 7 P	1			1		
Analog Signal Range ^e	V _{ANALOG}	V- = - 5 V	Full		- 5	8	- 5	8	V	
Drain-Source On-Resistance	r _{DS(on)}	$I_S = -10 \text{ mA}, V_D = 0 \text{ V}$	Room Full	45		90 120		90 120		
Resistance Match Between Channels	$\Delta r_{DS(on)}$	$V_{AIH} = 2.0 \text{ V}, V_{AIL} = 0.8 \text{ V}$ Sequence Each Switch On	Room	3		9		9	Ω	
Source Off Leakage Current	I _{S(off)}	$V_S = 8 \text{ V}, V_D = 0 \text{ V}, \overline{RS} = 0.8 \text{ V}$	Room Full		- 20 - 200	20 200	- 20 - 200	20 200		
Drain Off Leakage Current	I _{D(off)}	$V_D = 0 \text{ V}, V_S = 8 \text{ V}, \overline{RS} = 0.8 \text{ V}$	Room Full		- 20 - 200	20 200	- 20 - 200	20 200	nA	
Total Switch On Leakage Current	I _{D(on)}	$V_S = V_D = 8 V$	Room Full		- 20 - 2000	20 2000	- 20 - 200	20 200		
Digital Input/Output										
Input Voltage High	V_{AIH}		Full		2		2		V	
Input Voltage Low	V_{AIL}		Full			0.8		0.8	•	
Address Input Current	I _{AI}	$V_{AI} = 0 V \text{ or } 2 V \text{ or } 5 V$	Room Full	0.1	- 1 - 10	1 10	- 1 - 10	1 10		
Address Output Current	I _{AO}	V _{AO} = 2.7 V, See Truth Table	Room	- 600		- 200		- 200	μA	
Address Sulput Sulfont		V _{AO} = 0.4 V, See Truth Table	Room	1500	500		500			
DIS Pin Sink Current	I _{DIS}		Room	1.5					m/	
Dynamic Characteristics										
On State Input Capacitance ^e	C _{S(on)}	1 In to 1 Out, See Figure 11	Room	30				40		
On Otato Input Oupdonanoo		1 In to 4 Out, See Figure 11	Room	120				160		
Off State Input Capacitance ^e	C _{S(off)}	O =: 44	Room	8		20		20	pF	
Off State Output Capacitance ^e	C _{D(off)}	See Figure 11	Room	10		20		20		
Transition Time	t _{TRANS}	See Figure 5	Room					300	<u> </u>	
Break-Before-Make Interval	t _{OPEN}		Full			10		10		
SALVO, WR Turn On Time	t _{ON}	$R_L = 1 \text{ k}\Omega$, $C_L = 35 \text{ pF}$ 50 % Control to 90 % Output	Room Full			300 500		300	ns	
SALVO, WR Turn Off Time	t _{OFF}	See Figure 3	Room Full			175 300		175		
Charge Injection	Q	See Figure 6	Room	- 100					рС	
Matrix Disabled Crosstalk	X _{TALK(DIS)}	$R_{IN} = R_L = 75 \Omega$ f = 5 MHz, See Figure 10	Room	- 82						
Adjacent Input Crosstalk	X _{TALK(AI)}	R_{IN} = 10 Ω, R_L = 10 kΩ f = 5 MHz, See Figure 9	Room	- 85					dB	
All Hostile Crosstalk	X _{TALK(AH)}	$R_{IN} = 10 \Omega$, $R_{L} = 10 k\Omega$ f = 5 MHz, See Figure 8	Room	- 66						
Bandwidth	BW	R_L = 50 Ω, See Figure 7	Room	300					MH	





SPECIFICATIONS	Ī	Test Conditions			Λ 6	uffix	D G	uffix	
		Unless Specified				125 °C		uilix 85°C	Unit
		V+ = 15 V, V- = - 3 V			00 10				-
		$V_{L} = 5 \text{ V}, \overline{RS} = 2.0 \text{ V}$			l .				
Parameter	Symbol	\overline{SALVO} , \overline{CS} , \overline{WR} , $\overline{I}/O = 0.8 \text{ V}$	Temp ^b	Турс	Min ^d	Max ^d	Min ^d	Max ^d	Unit
Power Supplies						1		I	
Positive Supply Current	l+		Room Full	1.5		3 6		3 6	- mA
Negative Supply Current	I-	All Inputs at GND or 2 V	Room Full	- 1.5	- 3 - 5		- 3 - 5		IIIA
Digital GND Supply Current	I _{DG}	HS = 2 V	Full	- 275	- 750		- 750		μА
Logic Supply Current	ΙL		Full	200		500		500] .
Eupotional Operating	V+ to V- V- to GND See Operating Voltage Range (Typical Characteristics), page 6	Full		13	20	13	20		
Functional Operating Supply Voltage Range ^e		See Operating Voltage Hange (Typical Characteristics) page 6	Full		- 5.5	0	- 5.5	0	V
Supply vollage hallye	V+ to GND	(Typical Characteristics) page 0	Full		10	20	10	20	
Minimum Input Timing Ro	equirements								
Address Write Time	t_{AW}		Full	20	50		50		
Minimum WR Pulse Width	t _{WP}		Full	50	100		100		
Write Address Time	t _{WA}		Full	- 10	10		10		
Chip Select Write Time	t _{CW}		Full	50	100		100		
Write Chip Select Time	t _{WC}		Full	25	75		75		1
Minimum SALVO Pulse Width	t _{SP}		Full	50	100		100		
SALVO Write Time	t _{SW}	See Figure 1	Full	- 10	10		10		ns
Write SALVOTime	t _{WS}		Room	20			50		1
Input Output Time	t _{IO}		Room	150	200		200		1
Address Output Time	t _{AO}		Room	150	200		200		1
Chip Select Output Time	t _{CO}		Room	150	200		200		1
Chip Select Address Time	t _{CA}		Room	60			100		1
Reset to SALVO	t _{RS}		Full		50		50		1
I/O Address Input Time	t _{IA}		Room	50					1

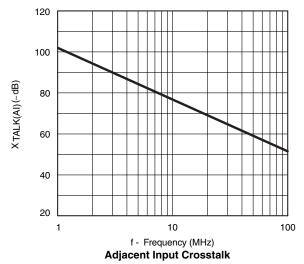
Notes:

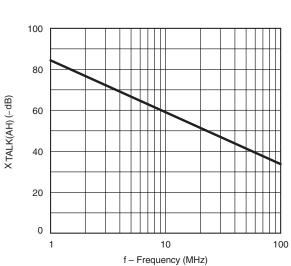
- a. Refer to PROCESS OPTION FLOWCHART.
- b. Room = 25 $^{\circ}$ C, Full = as determined by the operating temperature suffix.
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- e. Guaranteed by design, not subject to production test.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

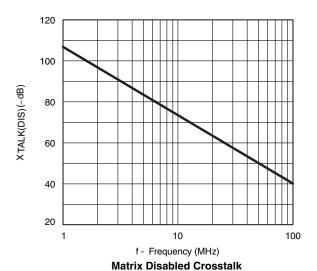
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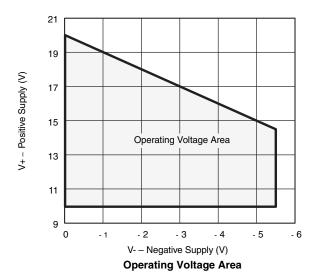
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





All Hostile Crosstalk







TIMING DIAGRAMS

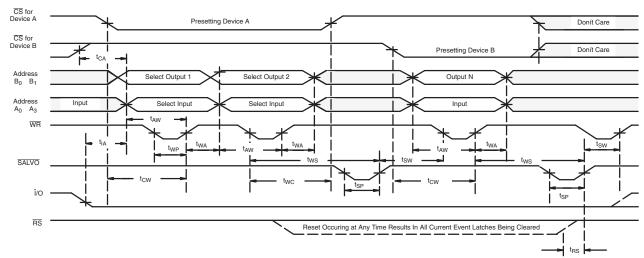


Figure 1. Input Timing Requirements

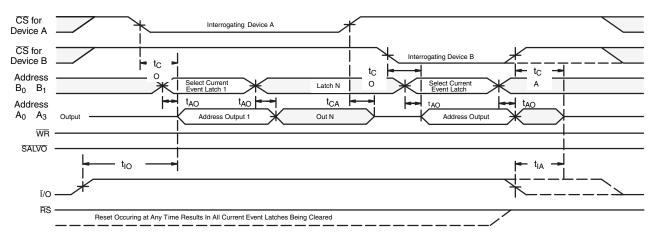


Figure 2. Output Timing Requirements

Symbol	Parameter	Description			
T _{AW}	Address to Write	Minimum time address must be valid before WR goes high			
T _{WA}	Write to Address	Minimum time address must remain valid after WR pulse goes high			
T _{WP}	WR Pulse	Minimum time of WR pulse width to write address into Next Event latches			
T _{CW}	Chip Select to WR	Minimum time chip select must be valid before a WR pulse			
T _{WC}	WR to Chip Select	Minimum time chip select must remain valid after WR pulse			
T _{SP}	SALVO Pulse	Minimum time of SALVO pulse width			
T _{WS}	WR to SALVO	Minimum time from WR pulse to SALVOto load new address			
T _{SW}	SALVO to WR	Minimum time from SALVO pulse to WR to load current address			
T _{IA}	Ī/O to Address In	Minimum time Ī/O must be valid before address applied			
T _{RS}	RS to SALVO	Minimum time RS must be valid before SALVO pulse			
T _{IO}	Ī/O to Output	Minimum time Ī/O must be valid before address output valid			
T _{AO}	Address to Output	Minimum time address B _X must be valid until address A _X output valid			
T _{CO}	CS to Output	Minimum time CS must be valid until A _X output is valid			
T _{CA}	CS to Address In	Minimum time $\overline{\text{CS}}$ must be valid before address applied if $\overline{\text{I/O}}$ is high			

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TEST CIRCUITS

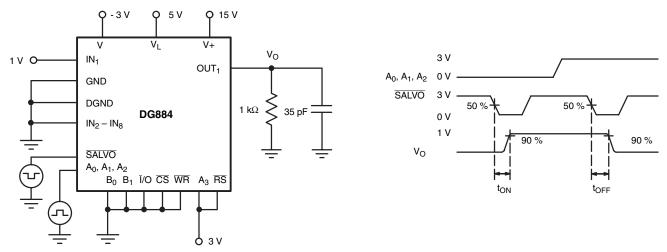


Figure 3. SALVO Turn On/Off Time

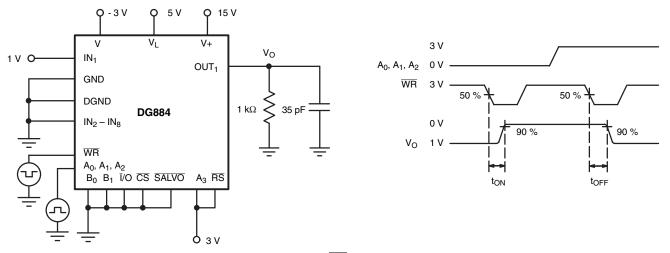


Figure 4. WR Turn On/Off Time

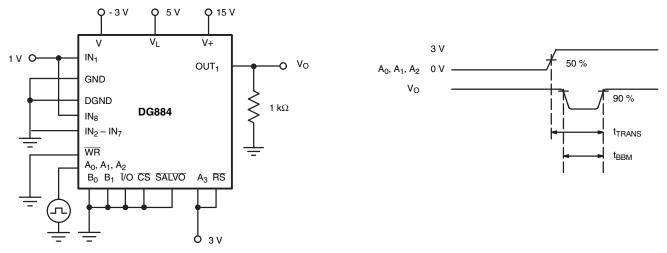


Figure 5. Transition Time and Break-Before-Make Interval



TEST CIRCUITS

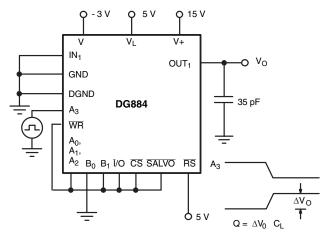


Figure 6. Charge Injection

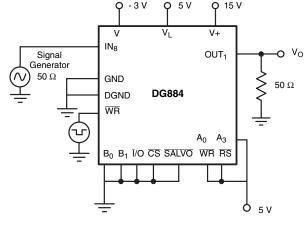


Figure 7. -3 dB Bandwidth

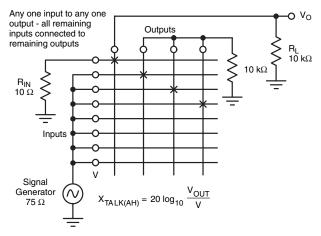


Figure 8. All Hostile Crosstalk

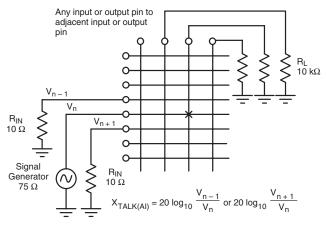


Figure 9. Adjacent Input Crosstalk

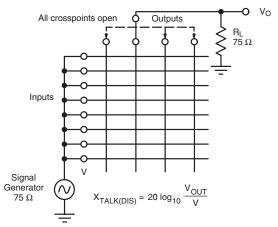


Figure 10. Matrix Disabled Crosstalk

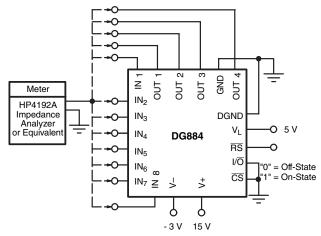


Figure 11. On-State and Off-State Capacitances



PIN DESCRIPTION							
Pin	Symbol	Description					
1, 3, 4, 6, 8, 10, 12, 14, 16, 18, 20, 41, 43	GND	Analog Signal Ground					
39	DGND	Digital Ground					
26	V+	Positive Supply Voltage					
21	V-	Negative Supply Voltage					
38	V_{L}	Logic Supply Voltage - generally 5 V					
5, 7, 9, 11, 13, 15, 17, 19	IN ₁ to IN ₈	8 Analog Input Channels					
2, 40, 42, 44	OUT ₁ to OUT ₄	4 Analog Output Channels					
29	Ī/O	Determines whether data is being written into the Next Event latches or read from the Current Event latches					
30	CS	Chip Select - a logic input					
31, 32, 33, 34	A ₀ , A ₁ , A ₂ , A ₃	IN Address - logic inputs or outputs as defined by Ī/O pin, select one of eight IN channels					
27, 28	B ₀ , B ₁	OUT Address - logic inputs, select one of four OUT channels					
35	WR	Write command that latches A ₀ , A ₁ , A ₂ , A ₃ into the Next Event latches					
36	SALVO	Master write command, that in one action, transfers all the data from Next Event latches into Current Event latches					
37	RS	Reset - a low will clear the Current Event latches					
22, 23, 24, 25	$\overline{\text{DIS}}_1$ to $\overline{\text{DIS}}_4$	Open drain disable outputs - these outputs pull low when the corresponding OUT channel is off					

DEVICE DESCRIPTION

The DG884 is the world's first monolithic wideband crosspoint array that operates from dc to > 100 MHz. The DG884 offers the ability to route any one of eight input signals to any one of four OUT pins. Any input can be routed to one, two, three or four OUTs simultaneously with no risk of shorting inputs together (guaranteed by design).

Each crosspoint is configured as a "T" switch in which DMOS FETs are used due to their excellent low resistance and low capacitance characteristics. Each OUT line has a series switch that minimizes capacitive loading when the OUT is off.

Interfacing

The DG884 was designed to allow complex matrices to be developed while maintaining a simple control interface. The status of the I/O pin determines whether the DG884 is being written to or read from (see Figures 1 and 2).

In order to WRITE to an individual latch, \overline{CS} and \overline{I}/O need to be low, while \overline{RS} , \overline{WR} and \overline{SALVO} must be high. The IN to OUT path is selected by using address A_0 through A_3 to define the IN line and address B_0 and B_1 to define the OUT line. That is, The IN defined by A_0 through A_3 is electrically connected to the OUT defined by B_0 , B_1 . This chosen path is loaded into the Next Event latches when \overline{WR} goes low and returns high again. This operation is repeated up to three more times if other crosspoint connections need to be changed.

Upon completing all crosspoint connections that are to be changed in a single device, other DG884s can be similarly preset by taking the $\overline{\text{CS}}$ pin low on the appropriate device. When all DG884s are preset, the Current Event latches are simultaneously changed by a single $\overline{\text{SALVO}}$ command applied to all devices. In this manner the crosspoint configuration of any number of devices can be simultaneously updated.

DIS Outputs

Four open drain disable OUTs are provided to control external line drivers or to provide visual or electrical signaling. For example, any or all of the DIS OUTs can directly interface with a CLC410 Video Amplifier to place it into a high impedance, low-power standby mode when the corresponding OUT is not being used. (See Figure 15). The $\overline{\text{DIS}}$ outputs are low and sink to V- when corresponding OUT is open or $\overline{\text{RS}}$ is low.

Reset

The reset function (\overline{RS}) allows the resetting of all crosspoints to a known state (open). At power up, the reset facility may be used to guarantee that all switches are open. It should be noted that \overline{RS} clears the Current Event latches, but the Next Event latches remain unchanged. This useful facility allows the user to return the matrix to its previous state (prior to reset) by simply applying the \overline{SALVO} command. Alternatively, the user can reprogram the Next Event latches, and then apply the \overline{SALVO} command to reconfigure the matrix to a new state.



DEVICE DESCRIPTION

Readback

The Ī/O facility enables the user to write data to the Next Event latches or to read the contents of the Current Event latches. This feature permits the central controller to periodically monitor the state of the matrix. If a power loss to

the controller occurs, the readback feature helps the matrix to recover rapidly. It also offers a means to perform PC board diagnostics both in production and in system operation.

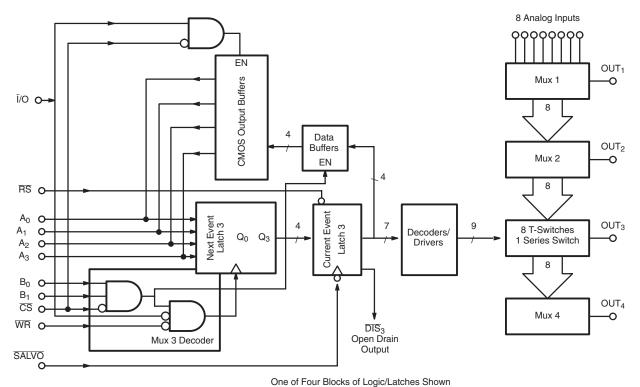


Figure 12. Control Circuitry

APPLICATIONS

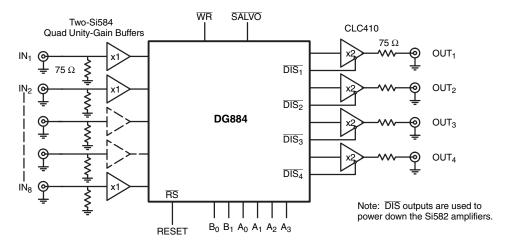


Figure 13. Fully Buffered 8 x 4 Crosspoint

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APPLICATIONS

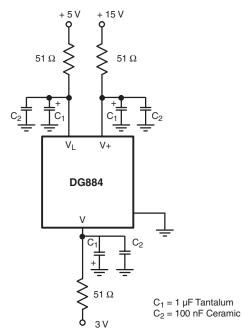


Figure 14. DG884 Power Supply Decoupling

6 5 V th - Logic Threshold (V) 4 3 2 1 0 0 2 6 8 10 12 16 V_L - Logic Supply (V)

Figure 15. Switching Threshold Voltage vs. VL

Power Supplies and Decoupling

A useful feature of the DG884 is its power supply flexibility. It can be operated from dual supplies, or a single positive supply (V- connected to 0 V) if required. Allowable operating voltage ranges are shown in Operating Voltage Range (Typical Characteristics) graph, page 6.

Note that the analog signal must not go below V- by more than 0.3 V (see absolute maximum ratings). However, the addition of a V- pin has a number of advantages:

- 1) It allows flexibility in analog signal handling, i.e. with $V-=-5\ V$ and $V+=15\ V$, up to $\pm\ 5\ V$ ac signals can be accepted.
- 2) The value of on-capacitance $[C_{S(on)}]$ may be reduced by increasing the value of V-. It is useful to note that optimum video differential phase and gain occur when V- is 3 V. Note that V+ has no effect on $C_{S(on)}$.
- V- eliminates the need to bias an ac analog signal using potential dividers and large decoupling capacitors.

It is established RF design practice to incorporate sufficient bypass capacitors in the circuit to decouple the power supplies to all active devices in the circuit. The dynamic performance of the DG884 is adversely affected by poor decoupling of power supply pins. Also, since the substrate of the device is connected to the negative supply, proper decoupling of this pin is essential.

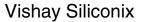
Rules:

- Decoupling capacitors should be incorporated on all power supply pins (V+, V-, V₁).
- They should be mounted as close as possible to the device pins.
- Capacitors should have good high frequency characteristics - tantalum bead and/or monolithic ceramic disc types are suitable.

Recommended decoupling capacitors are 1 to 10 μ F tantalum bead, in parallel with 100 nF monolithic ceramic.

4) Additional high frequency protection may be provided by 51 Ω carbon film resistors connected in series with the power supply pins (see Figure 14).

The V_L pin permits interface to various logic types. The device is primarily designed to be TTL or CMOS logic compatible with + 5 V applied to V_L . The actual logic threshold can be raised simply by increasing V_L .





APPLICATIONS

A typical switching threshold versus V_L is shown in Figure 15.

These devices feature an address readback facility whereby the last address written to the device may be read by the system. This allows improved status monitoring and hand shaking without additional external components.

When the \overline{I}/O assigns the address output condition, the A_X address pins can sink or source current for logic low and high, respectively. Note that V_L is the logic high output condition. This point must be respected if V_L is varied for input logic threshold shifting.

Note: Even though these devices are designed to be latchup resistant, V_L must not exceed V+ by more than 0.3 V in operation or during power supply on/off sequencing.

Layout

The PLCC package pinout is optimized so that large crosspoint arrays can be easily implemented with a minimum number of PCB layers (see Figure 16). Crosstalk is minimized and off-isolation is optimized by having ground pins located adjacent to each input and output signal pins. Optimum off-isolation and low crosstalk performance can only be achieved by the proper use of RF layout techniques: avoid sockets, use ground planes, avoid ground loops, bypass the power supplies with high frequency type capacitors (low ESR, low ESL), use striplines to maintain transmission line impedance matching.

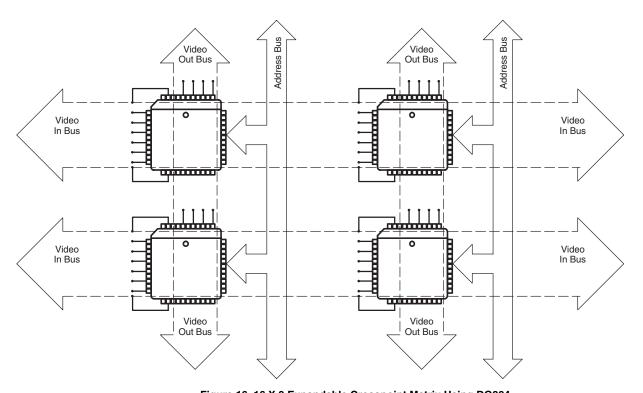


Figure 16. 16 X 8 Expandable Crosspoint Matrix Using DG884

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Revision: 18-Jul-08

Document Number: 91000 www.vishay.com